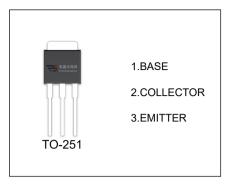


# 2SC2983 TRANSISTOR (NPN)

#### **FEATURES**

High Transition Frequency



### MAXIMUM RATINGS (T<sub>a</sub>=25°C unless otherwise noted)

| Symbol                           | Parameter  | Value    | Unit |
|----------------------------------|--|----------|------|
| V <sub>CBO</sub>                 | Collector-Base Voltage                           | 160      | V    |
| V <sub>CEO</sub>                 | Collector-Emitter Voltage                        | 160      | V    |
| V <sub>EBO</sub>                 | Emitter-Base Voltage                             | 5        | V    |
| Ic                               | Collector Current                                | 1.5      | Α    |
| Pc                               | Collector Power Dissipation                      | 1        | W    |
| R <sub>0JA</sub>                 | Thermal Resistance From Junction To Ambient      | 125      | °C/W |
| T <sub>J</sub> ,T <sub>stg</sub> | Operation Junction and Storage Temperature Range | -55~+150 | °C   |

## **ELECTRICAL CHARACTERISTICS (T<sub>a</sub>=25°C unless otherwise specified)**

| Parameter                            | Symbol                 | Test conditions                                | Min | Тур | Max | Unit |
|--------------------------------------|------------------------|--|-----|-----|-----|------|
| Collector-base breakdown voltage     | $V_{(BR)CBO}$          | I <sub>C</sub> =1mA,I <sub>E</sub> =0          | 160 |     |     | V    |
| Collector-emitter breakdown voltage  | V <sub>(BR)CEO</sub> * | I <sub>C</sub> =10mA,I <sub>B</sub> =0         | 160 |     |     | V    |
| Emitter-base breakdown voltage       | $V_{(BR)EBO}$          | I <sub>E</sub> =1mA,I <sub>C</sub> =0          | 5   |     |     | V    |
| Collector cut-off current            | I <sub>CBO</sub>       | V <sub>CB</sub> =160V,I <sub>E</sub> =0        |     |     | 1   | μΑ   |
| Emitter cut-off current              | I <sub>EBO</sub>       | V <sub>EB</sub> =5V,I <sub>C</sub> =0          |     |     | 1   | μΑ   |
| DC current gain                      | h <sub>FE</sub>        | V <sub>CE</sub> =5V, I <sub>C</sub> =100mA     | 70  |     | 240 |      |
| Collector-emitter saturation voltage | $V_{CE(sat)}$          | I <sub>C</sub> =500mA,I <sub>B</sub> =50mA     |     |     | 1.5 | ٧    |
| Base-emitter voltage                 | $V_{BE}$               | V <sub>CE</sub> =5V, I <sub>C</sub> =500mA     |     |     | 1   | ٧    |
| Collector output capacitance         | C <sub>ob</sub>        | V <sub>CB</sub> =10V,I <sub>E</sub> =0, f=1MHz |     | 25  |     | pF   |
| Transition frequency                 | $f_{T}$                | V <sub>CE</sub> =10V,I <sub>C</sub> =100mA,    |     | 100 |     | MHz  |

<sup>\*</sup>Pulse test

### **CLASSIFICATION OF h**<sub>FE</sub>

| RANK  | 0      | Y       |
|-------|--------|---------|
| RANGE | 70-140 | 120-240 |



